

October 1988 Revised March 1999

74F2244 Octal Buffer/Line Driver with 25 Ω Series Resistors in Outputs

General Description

The F2244 is an octal buffer/line driver designed to drive the capacitive inputs of MOS memory drivers, address drivers, clock drivers and bus-oriented transmitters/receivers.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

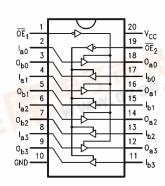
- 3-STATE outputs drive bus lines or buffer memory address registers
- 12 mA source current
- \blacksquare 25 Ω series resistors in outputs eliminate the need for external resistors.
- Designed to drive the capacitive inputs of MOS devices
- Guaranteed 4000V minimum ESD protection

Ordering Code:

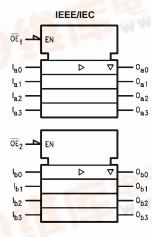
Order Number	Package Number	Package Description
74F2244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F2244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F2244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol





Unit Loading/Fan Out

Pin Names	Description	U.L.	Input I _{IH} /I _{IL}		
		HIGH/LOW	Output I _{OH} /I _{OL}		
\overline{OE}_1 , \overline{OE}_2	3-STATE Output Enable Input (Active LOW)	1.0/1.667	20 μA/–1 mA		
OE ₂	3-STATE Output Enable Input (Active HIGH)	1.0/1.667	20 μA/–1 mA		
I _{an} , I _{bn}	Inputs	1.0/2.667 (Note 1)	20 μA/–1.6 mA		
O _{an} ,O _{bn}	Outputs	750/20	–15 mA/12 mA		

Note 1: Worst-case F2244 disabled

Truth Table

OE ₁	I _{an}	O _{an}	OE ₂	I _{bn}	O _{bn}	
Н	X	Z	Н	X	Z	
L	Н	Н	L	Н	Н	
L	L	L	L	L	L	

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 2)

Recommended Operating Conditions

 $\begin{array}{ll} \mbox{Storage Temperature} & -65\mbox{°C to } +150\mbox{°C} \\ \mbox{Ambient Temperature under Bias} & -55\mbox{°C to } +125\mbox{°C} \\ \end{array}$

Ambient Temperature under Bias -55°C to +125°C

Junction Temperature under Bias -55°C to +150°C

 V_{CC} Pin Potential to Ground Pin -0.5V to +7.0VInput Voltage (Note 3) -0.5V to +7.0VInput Current (Note 3) -30 mA to +5.0 mA

Voltage Applied to Output

in HIGH State (with $V_{CC} = 0V$)

 $\begin{array}{ll} \mbox{Standard Output} & -0.5\mbox{V to V}_{\mbox{CC}} \\ \mbox{3-STATE Output} & -0.5\mbox{V to } +5.5\mbox{V} \end{array}$

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA) ESD Last Passing Voltage (Min) 4000V

Free Air Ambient Temperature $0^{\circ}\text{C} \text{ to } +70^{\circ}\text{C}$ Supply Voltage +4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

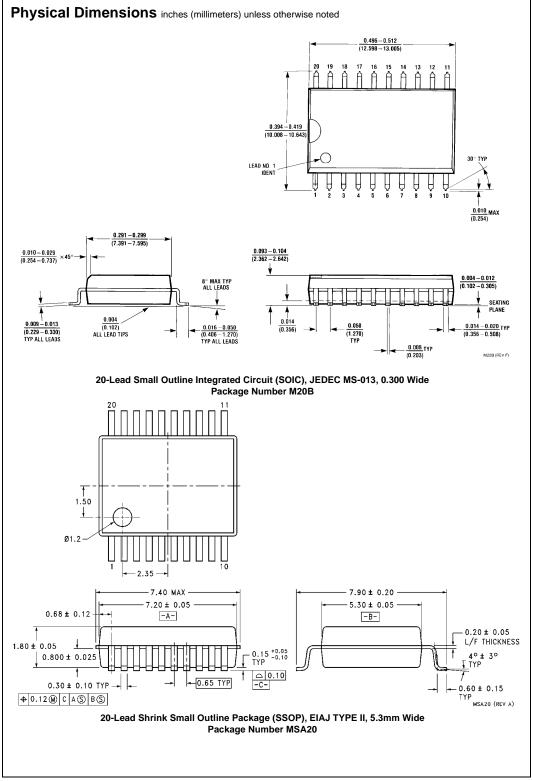
Note 3: Either voltage limit or current limit is sufficient to protect inputs.

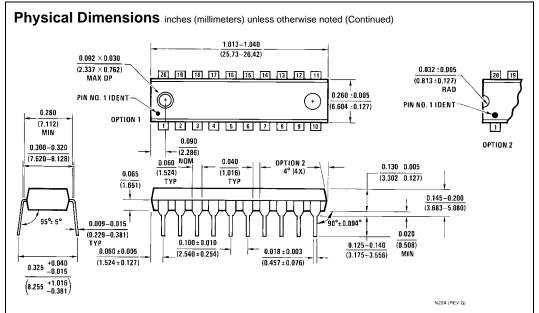
DC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Units	v _{cc}	Conditions
V _{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage 10% V _{C0}	2.4			V	Min	$I_{OH} = -3 \text{ mA}$
	10% V _{CC}	2.0					$I_{OH} = -15 \text{ mA}$
	5% V _{CC}	2.7					$I_{OH} = -3 \text{ mA}$
V _{OL}	Output LOW Voltage			0.50	V	Min	I _{OL} = 1 mA
				0.75			$I_{OL} = 12 \text{ mA}$
I _{IH}	Input HIGH Current			5.0	μΑ	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test			7.0	μΑ	Max	V _{IN} = 7.0V
I _{CEX}	Output HIGH Leakage Current			50	μΑ	Max	$V_{OUT} = V_{CC}$
V _{ID}	Input Leakage	4.75			V	0.0	$I_{ID} = 1.9 \mu\text{A}$
	Test						All other pins grounded
I _{OD}	Output Leakage			3.75	μΑ	0.0	$V_{IOD} = 150 \text{ mV}$
	Circuit Current						All other pins grounded
I _{IL}	Input LOW Current			-1.0	mA	Max	$V_{IN} = 0.5V (\overline{OE}_1, \overline{OE}_2, OE_2)$
				-1.6			$V_{IN} = 0.5V (I_n)$
I _{OZH}	Output Leakage Current			50	μА	Max	V _{OUT} = 2.7V
I _{OZL}	Output Leakage Current			-50	μА	Max	V _{OUT} = 0.5V
Ios	Output Short-Circuit Current	-100		-225	mA	Max	V _{OUT} = 0V
I _{CCH}	Power Supply Current		40	60	mA	Max	V _O = HIGH
I _{CCL}	Power Supply Current		60	90	mA	Max	$V_O = LOW$
I _{CCZ}	Power Supply Current		60	90	mA	Max	V _O = HIGH Z

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$			$T_A = -55^{\circ}\text{C to } +125^{\circ}\text{C}$ $C_L = 50 \text{ pF}$		$T_A = 0$ °C to +70°C $C_L = 50 \text{ pF}$		Units
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay	1.5		7.0	2.0	6.5	1.5	7.0	ns
t _{PHL}	Data to Output	2.5		8.0	2.0	7.0	2.0	8.0	
t _{PZH}	Output Enable Time	1.5		9.0	2.0	7.0	1.0	9.5	
t_{PZL}		2.5		11.5	2.0	8.5	2.5	12.0	ns
t _{PHZ}	Output Disable Time	1.5		9.0	2.0	7.0	1.0	9.5	
t_{PLZ}		1.5		8.5	2.0	7.5	1.5	9.5	





20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide Package Number N20A

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